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SCES573B-JUNE 2004-REVISED JULY 2013

OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

Check for Samples: SN74LV541AT

FEATURES

- Inputs Are TTL-Voltage Compatible
- 4.5-V to 5.5-V V_{CC} Operation
- Typical t_{pd} of 4 ns at 5 V
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 5 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2.3 V at V_{CC} = 5 V, T_A = 25°C
- Supports Mixed-Mode Voltage Operation on All Ports
- Ioff Supports Partial-Power-Down Mode
 Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION

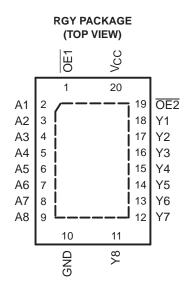
The SN74LV541AT is designed for 4.5-V to 5.5-V V_{CC} operation. The inputs are TTL-voltage compatible, which allows them to be interfaced with bipolar outputs and 3.3-V devices. The device also can be used to translate from 3.3 V to 5 V.

This device is ideal for driving bus lines or buffer memory address registers. It features inputs and outputs on opposite sides of the package to facilitate printed circuit board layout.

The 3-state control gate is a two-input AND gate with active-low inputs so that, if either output-enable ($\overline{OE1}$ or $\overline{OE2}$) input is high, all corresponding outputs are in the high-impedance state. The outputs provide noninverted data when they are not in the high-impedance state.

To ensure the high-impedance state during power up or power down, OE shall be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



DB, DGV, DW, NS, OR PW PACKAGE

	(TOP V	IEW)	
OE1	1	20	Vcc
A1 [2	19] <u>OE2</u>
A2 [3	18] Y1
A3 🛛	4	17] Y2
A4 [5	16] Y3
A5 [6	15] Y4
A6 [7	14] Y5
A7 [A8 [8	13] Y6
A8 [9	12] Y7
GND [10	11] Y8

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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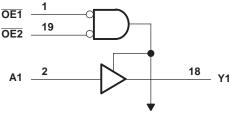
This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

FUNCTION TABLE (EACH BUFFER/DRIVER)

	INPUTS		OUTPUT
OE1	OE2	Α	Y
L	L	L	L
L	L	н	н
н	Х	Х	Z
Х	Н	Х	Z

LOGIC DIAGRAM (POSITIVE LOGIC)



To Seven Other Channels

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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any output in the	high-impedance or power-off state ⁽²⁾	-0.5	7	V
Vo	Output voltage range applied in the high o	r low state ⁽²⁾⁽³⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-20	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
lo	Continuous output current	$V_{O} = 0$ to V_{CC}		±35	mA
	Continuous current through V_{CC} or GND			±70	mA
		DB package ⁽⁴⁾		70	
		DGV package ⁽⁴⁾		92	
~		DW package ⁽⁴⁾		58	0 0 AA/
θ_{JA}	Package thermal impedance	NS package ⁽⁴⁾		60	°C/W
		PW package ⁽⁴⁾		83	
		RGY package ⁽⁵⁾		37	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) This value is limited to 5.5 V maximum.

(4) The package thermal impedance is calculated in accordance with JESD 51-7

(5) The package thermal impedance is calculated in accordance with JESD 51-5.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage		4.5	5.5	V
VIH	High-level input voltage	V_{CC} = 4.5 V to 5.5 V	2		V
V _{IL}	Low-level input voltage	V_{CC} = 4.5 V to 5.5 V		0.8	V
VI	Input voltage		0	5.5	V
V	Output voltage	High or low state	0	V_{CC}	V
Vo	Output voltage	3-state	0	5.5	v
I _{OH}	High-level output current	V_{CC} = 4.5 V to 5.5 V		-16	mA
I _{OL}	Low-level output current	V_{CC} = 4.5 V to 5.5 V		16	mA
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 4.5 V \text{ to } 5.5 V$		20	ns/V
T _A	Operating free-air temperature		-40	125	°C

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			-	[₄ = 25°C		T ₄ = −40°C to	95%	$T_A = -4$	10°C to	125°C	
PARAMET	TEST CONDITIONS				•	$T_{A} = -40 \text{ C to}$	Rec	ommen	ded	UNIT	
ER	TEST CONDITIONS	V _{cc}	SN74LV541AT			SN74LV54	SN7	4LV541	AT	UNIT	
			MIN	TYP	MAX	MIN	MAX	MIN	TYP	MAX	
V	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		4.4			V
V _{OH}	I _{OH} = -16 mA	4.5 V	3.8			3.8		3.8			v
V	$I_{OL} = 50 \ \mu A$	4.5 V		0	0.1		0.1			0.1	V
V _{OL}	I _{OL} = 16 mA	4.5 V			0.55		0.55			0.55	v
I _I	$V_{I} = 5.5 \text{ V or GND}$	0 to 5.5 V			±0.1		±1			±1	μA
I _{OZ}	$V_{O} = V_{CC}$ or GND	5.5 V			±0.25		±2.5			±2.5	μA
I _{CC}	$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	5.5 V			2		20			20	μA
ΔI_{CC} ⁽¹⁾	One input at 3.4 V, Other inputs at $V_{CC} \mbox{ or } GND$	5.5 V			1.35		1.5			150	mA
I _{off}	$V_1 \text{ or } V_0 = 0 \text{ to } 5.5 \text{ V}$	0			0.5		5			5	μA
Ci	$V_1 = V_{CC}$ or GND			2							pF

(1) This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

	FROM	то	LOAD	T _A = 25°C T		T _A = −40°C to 85°C		T _A = 25°C to 125°C				
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE				65°C		Recommended			UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	TYP	MAX	
t _{pd}	A	Y		2.6	5	6.9	1	8	1		9	
t _{en}	OE	Y	C _L = 15 pF	3	8.3	11.3	1	13	1		14	ns
t _{dis}	OE	Y		1.4	3.9	7.5	1	8	1		8.5	
t _{pd}	A	Y		4	5.5	7.9	1	9	1		10	
t _{en}	OE	Y	C = 50 pF	3.8	8.8	12.3	1	14	1		15.2	20
t _{dis}	OE	Y	C _L = 50 pF	2.1	9.4	11.9	1	13.5	1		14	ns
t _{sk(o)}						1		1				

NOISE CHARACTERISTICS⁽¹⁾

 $V_{CC} = 5 \text{ V}, \text{ C}_{L} = 50 \text{ pF}$

	PARAMETER	Т	_A = 25°	С	
	PARAMEIER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		1.1	1.5	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-1.1	-1.5	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4		V
V _{IH(D)}	High-level dynamic input voltage	2			V
V _{IL(D)}	Low-level dynamic input voltage			0.8	V

(1) Characteristics are for surface-mount packages only.

OPERATING CHARACTERISTICS

 $V_{CC} = 5 V, T_A = 25^{\circ}C$

	PARAMETER	TEST CO	TYP	UNIT		
\mathbf{C}_{pd}	Power dissipation capacitance	Outputs enabled	$C_{L} = 50 \text{ pF},$	f = 10 MHz	8	pF

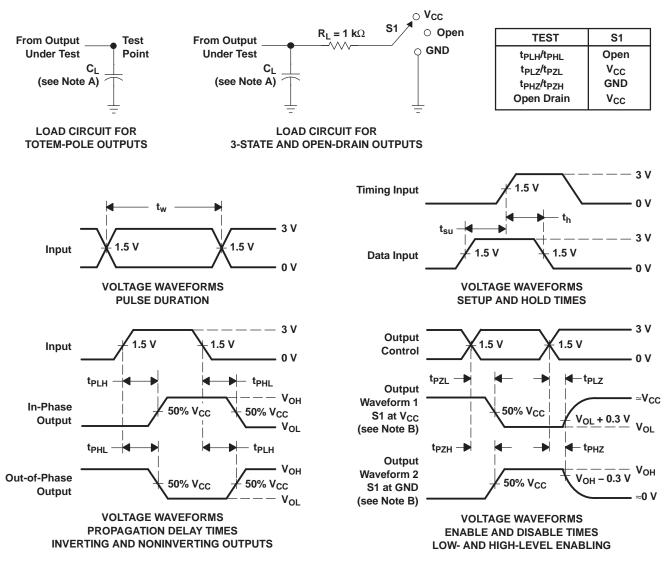


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SN74LV541AT

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. CL includes probe and jig capacitance.

 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_Q = 50 Ω, t_f ≤ 3 ns, t_f ≤ 3 ns.

- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- 1. $t_{P/L}$ and $t_{P/L}$ are the same as t_{en} .
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuits and Voltage Waveforms

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REVISION HISTORY

Cł	nanges from Revision A (August 2005) to Revision B	Page	ļ
•	Added parameter values for -40 to 125°C temperature ratings.	4	



10-Jun-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV541ATDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541AT	Samples
SN74LV541ATDGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541AT	Samples
SN74LV541ATDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541AT	Samples
SN74LV541ATDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541AT	Samples
SN74LV541ATNSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV541AT	Samples
SN74LV541ATPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541AT	Samples
SN74LV541ATPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541AT	Samples
SN74LV541ATPWT	ACTIVE	TSSOP	PW	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541AT	Samples
SN74LV541ATRGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	VV541	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)



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PACKAGE OPTION ADDENDUM

10-Jun-2014

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



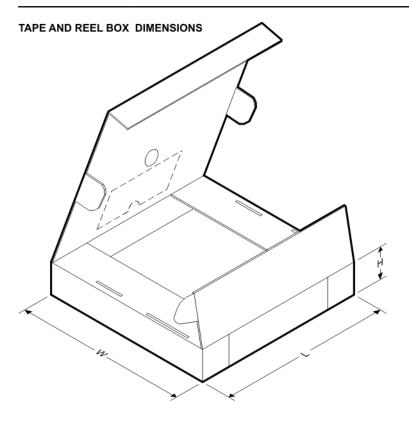
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV541ATDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LV541ATDGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV541ATDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LV541ATNSR	SO	NS	20	2000	330.0	24.4	9.0	13.0	2.4	12.0	24.0	Q1
SN74LV541ATPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LV541ATPWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LV541ATRGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

17-Aug-2016



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV541ATDBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74LV541ATDGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0
SN74LV541ATDWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LV541ATNSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LV541ATPWR	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74LV541ATPWT	TSSOP	PW	20	250	367.0	367.0	38.0
SN74LV541ATRGYR	VQFN	RGY	20	3000	367.0	367.0	35.0

DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



MECHANICAL DATA



- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (R-PVQFN-N20)

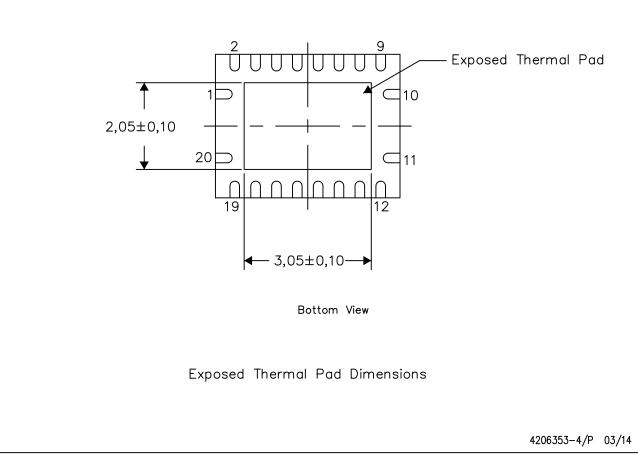
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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